

HIGH ISOLATION VOLTAGE SINGLE TRANSISTOR TYPE MULTI PHOTOCOUPLER SERIES

–NEPOC Series–

DESCRIPTION

- ★ The PS2561A-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor to realize an excellent cost performance.

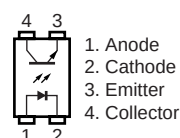
The PS2561A-1 is in a plastic DIP (Dual In-line Package) and the PS2561AL-1 is lead bending type (Gull-wing) for surface mount.

The PS2561AL1-1 is lead bending L1 type and the PS2561AL2-1 is lead bending L2 type (Gull-wing).

FEATURES

- ★
 - Lead-free product : Solder plating specification Sn-Bi
 - High isolation voltage (BV = 5 000 Vr.m.s.)
 - Ordering number of taping product: PS2561AL-1-E3, E4, F3, F4
: PS2561AL2-1-E3, E4
- Safety standards
 - UL, BSI, CSA, NEMKO, DEMKO, SEMKO, FIMKO, approved
- ★
 - DIN EN60747-5-2 (VDE0884 Part2) approved (option)

PIN CONNECTION (Top View)



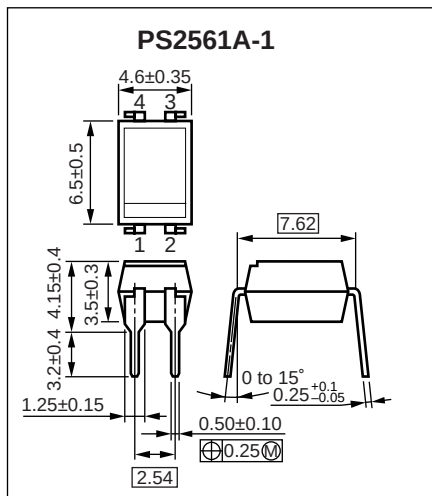
APPLICATIONS

- Power supply
- Telephone/FAX.
- FA/OA equipment
- Programmable logic controller

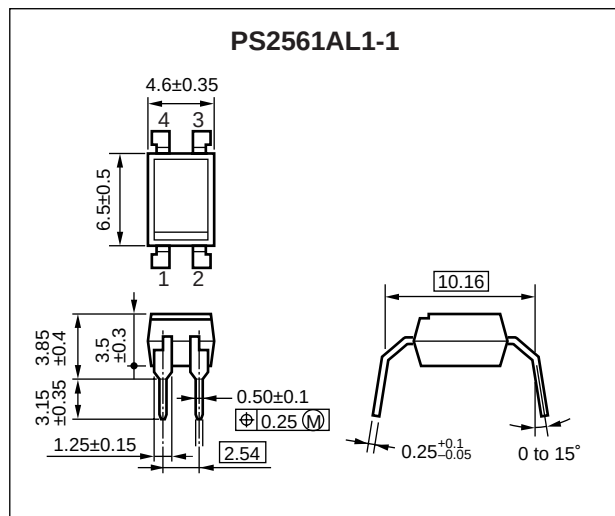
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 Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

PACKAGE DIMENSIONS (UNIT : mm)

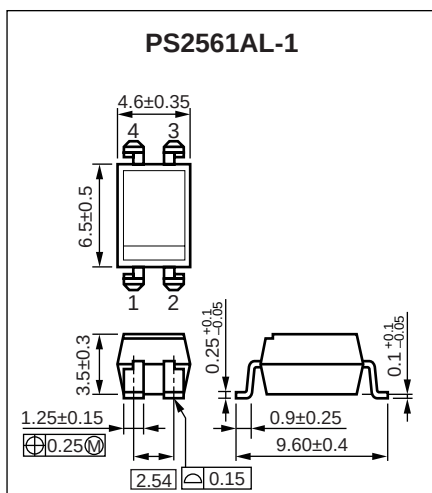
DIP Type



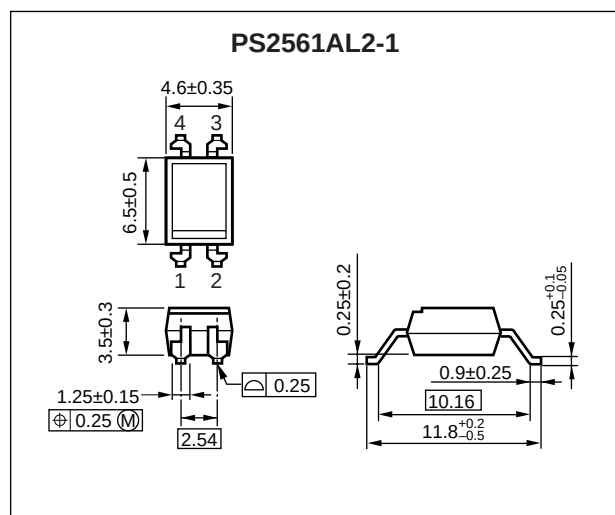
Long Creepage Distance



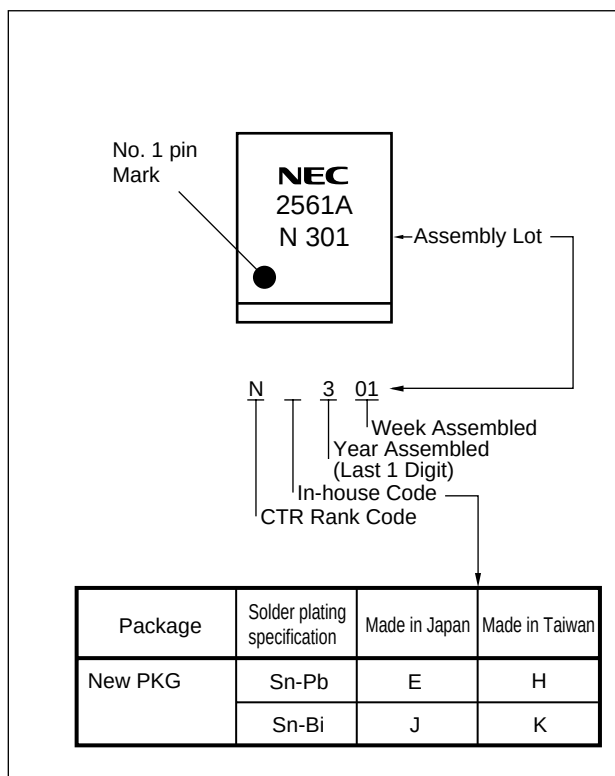
Lead Bending Type



Long Creepage Distance (Gull-Wing)



★ MARKING EXAMPLE



★ ORDERING INFORMATION (1/2)

Part Number	Package	Packing Style	Safety Standard Approval	Solder plating Specification	Application Part Number ^{*1}
PS2561A-1	4-pin DIP	Magazine case 100 pcs	Standard products (UL, CSA, BSI, NEMKO, DEMKO, SEMKO, FIMKO approved)	Sn-Pb	PS2561A-1
PS2561AL-1					
PS2561AL1-1					
PS2561AL2-1					
PS2561AL-1-E3					
PS2561AL-1-E4					
PS2561AL2-1-E3					
PS2561AL2-1-E4					
PS2561AL-1-F3					
PS2561AL-1-F4					
PS2561A-1-V		Magazine case 100 pcs	DIN EN60747-5-2 (VDE0884 Part2) Approved products (option)		
PS2561AL-1-V					
PS2561AL1-1-V					
PS2561AL2-1-V					
PS2561AL-1-V-E3					
PS2561AL-1-V-E4					
PS2561AL2-1-V-E3					
PS2561AL2-1-V-E4					
PS2561AL-1-V-F3					
PS2561AL-1-V-F4					
PS2561A-1-A	Magazine case 100 pcs	Standard products (UL, CSA, BSI, NEMKO, DEMKO, SEMKO, FIMKO approved)	Sn-Bi		
PS2561AL-1-A					
PS2561AL1-1-A					
PS2561AL2-1-A					
PS2561AL-1-E3-A					
PS2561AL-1-E4-A					
PS2561AL2-1-E3-A					
PS2561AL2-1-E4-A					
PS2561AL-1-F3-A					
PS2561AL-1-F4-A					

*1 For the application of the Safety Standard, following part number should be used.

★ ORDERING INFORMATION (2/2)

Part Number	Package	Packing Style	Safety Standard Approval	Solder plating Specification	Application Part Number ^{*1}
PS2561A-1-V-A	4-pin DIP	Magazine case 100 pcs	DIN EN60747-5-2 (VDE0884 Part2) Approved products (option)	Sn-Bi	PS2561A-1
PS2561AL-1-V-A					
PS2561AL1-1-V-A					
PS2561AL2-1-V-A					
PS2561AL-1-V-E3-A		Embossed Tape 1 000 pcs/reel			
PS2561AL-1-V-E4-A					
PS2561AL2-1-V-E3-A		Embossed Tape 1 000 pcs/reel			
PS2561AL2-1-V-E4-A					
PS2561AL-1-V-F3-A		Embossed Tape 2 000 pcs/reel			
PS2561AL-1-V-F4-A					

*1 For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Reverse Voltage	V _R	6	V
	Forward Current (DC)	I _F	30	mA
	Power Dissipation Derating	ΔP _D /°C	1.5	mW/°C
	Power Dissipation	P _D	150	mW
	Peak Forward Current ^{*1}	I _{FP}	0.5	A
Transistor	Collector to Emitter Voltage	V _{CEO}	70	V
	Emitter to Collector Voltage	V _{ECO}	5	V
	Collector Current	I _C	30	mA
	Power Dissipation Delay	ΔP _C /°C	1.5	mW/°C
	Power Dissipation	P _C	150	mW
Isolation Voltage ^{*2}		BV	5 000	Vr.m.s.
Operating Ambient Temperature		T _A	–55 to +100	°C
Storage Temperature		T _{stg}	–55 to +150	°C

***1** PW = 100 μs, Duty Cycle = 1%

***2** AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output

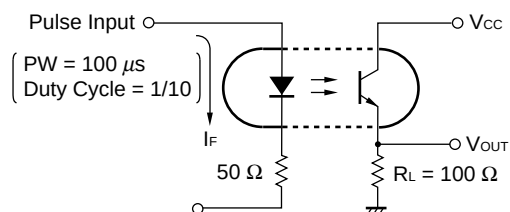
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V _F	I _F = 10 mA		1.2	1.4	V
	Reverse Current	I _R	V _R = 5 V			5	μA
	Terminal Capacitance	C _t	V = 0 V, f = 1.0 MHz		10		pF
Transistor	Collector to Emitter Dark Current	I _{CEO}	V _{CE} = 70 V, I _F = 0 mA			100	nA
Coupled	Current Transfer Ratio (I _C /I _F) ^{*1}	CTR	I _F = 5 mA, V _{CE} = 5 V	50		300	%
	Collector Saturation Voltage	V _{CE(sat)}	I _F = 10 mA, I _C = 2 mA		0.13	0.3	V
	Isolation Resistance	R _{I-O}	V _{I-O} = 1.0 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time ^{*2}	t _r	V _{CC} = 10 V, I _C = 2 mA, R _L = 100 Ω		5		μs
	Fall Time ^{*2}	t _f			7		

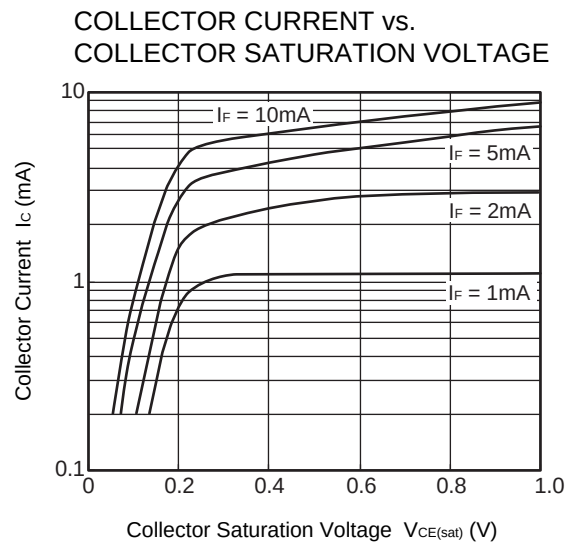
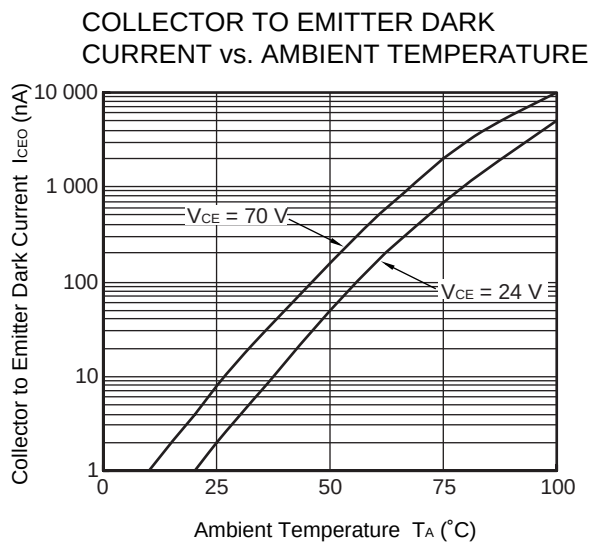
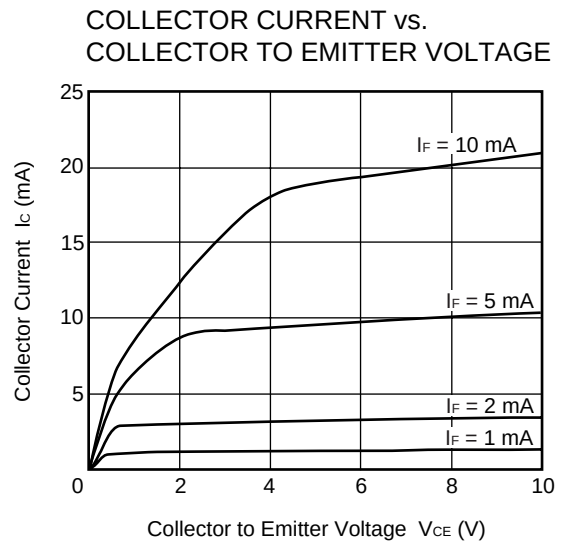
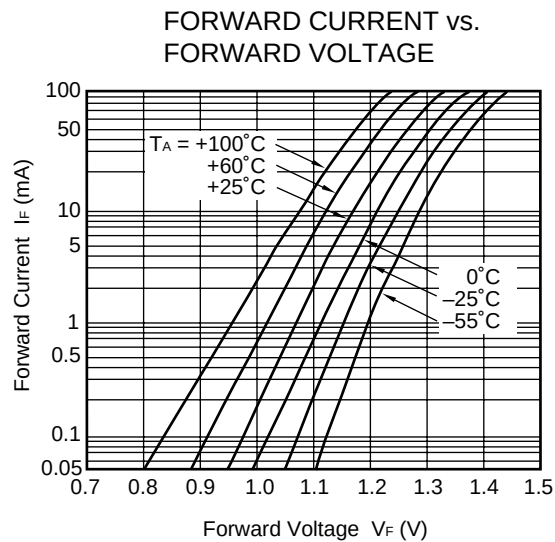
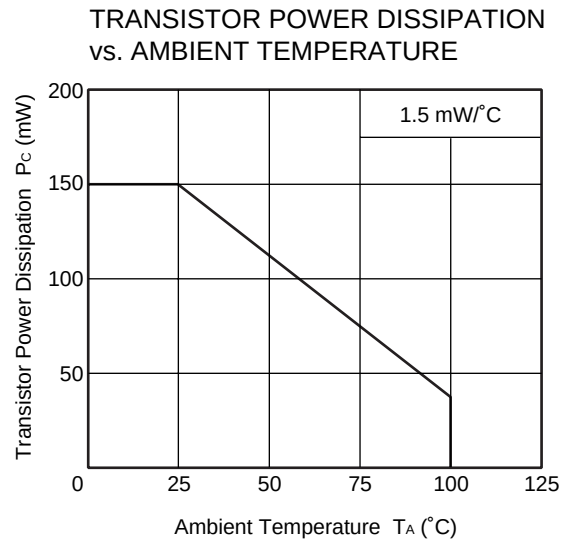
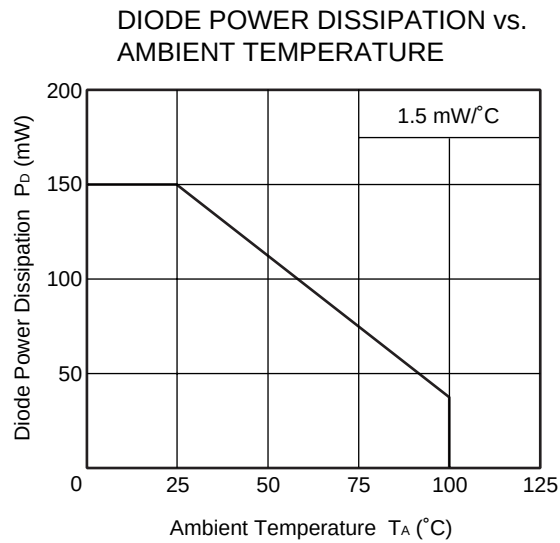
*1 CTR rank

- N : 50 to 300 (%)
- H : 80 to 160 (%)
- Q : 100 to 200 (%)
- W : 130 to 260 (%)

*2 Test circuit for switching time

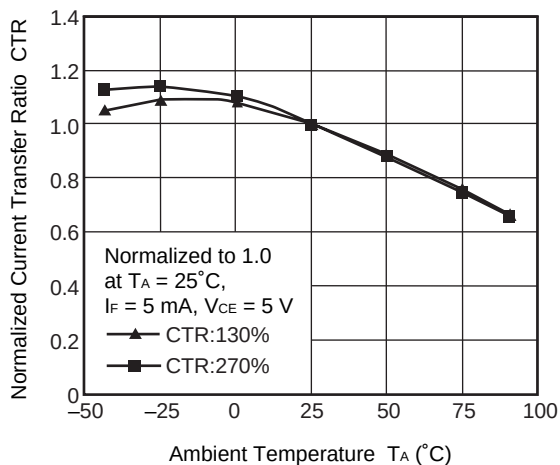


TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

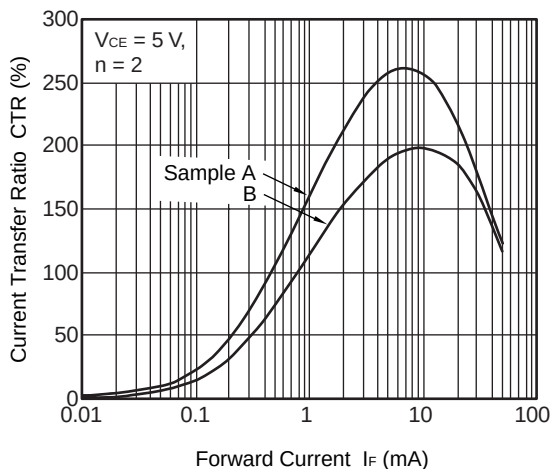


Remark The graphs indicate nominal characteristics.

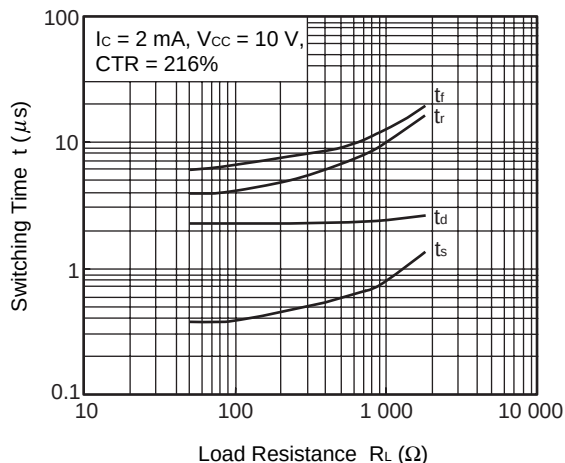
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



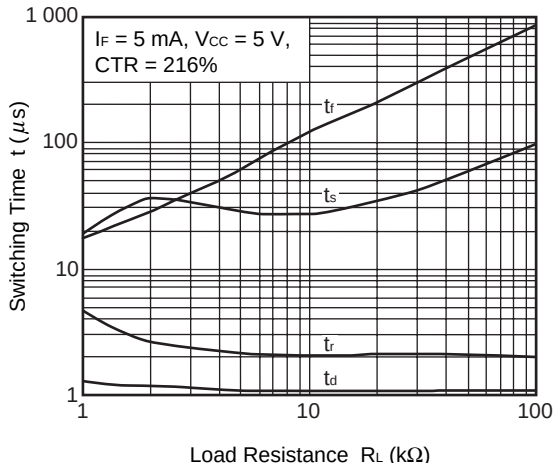
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



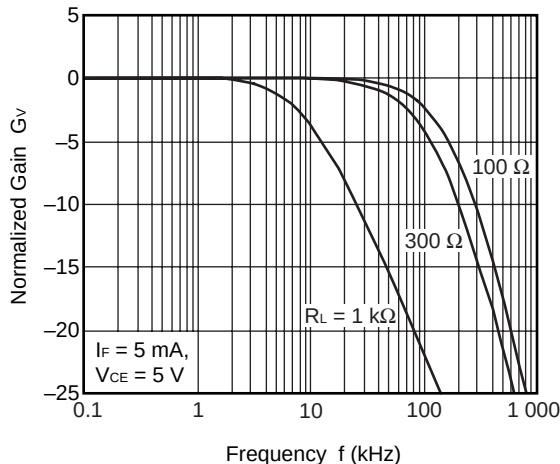
SWITCHING TIME vs. LOAD RESISTANCE



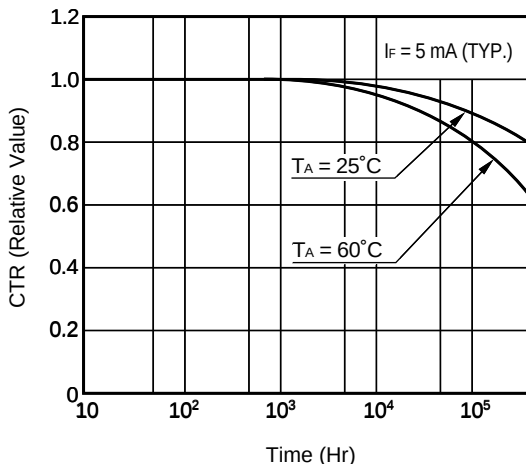
SWITCHING TIME vs. LOAD RESISTANCE



FREQUENCY RESPONSE



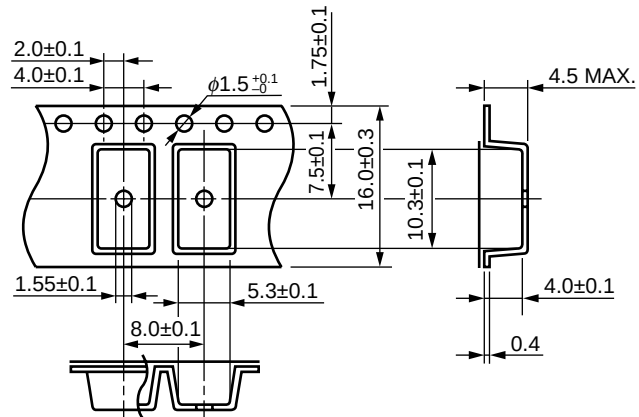
LONG TERM CTR DEGRADATION



Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT : mm)

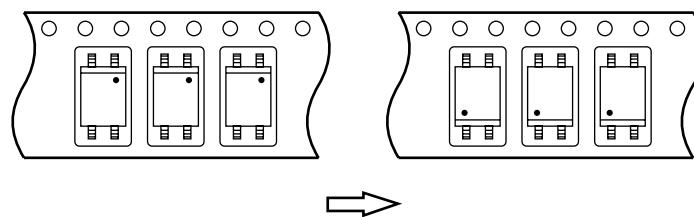
Outline and Dimensions (Tape)



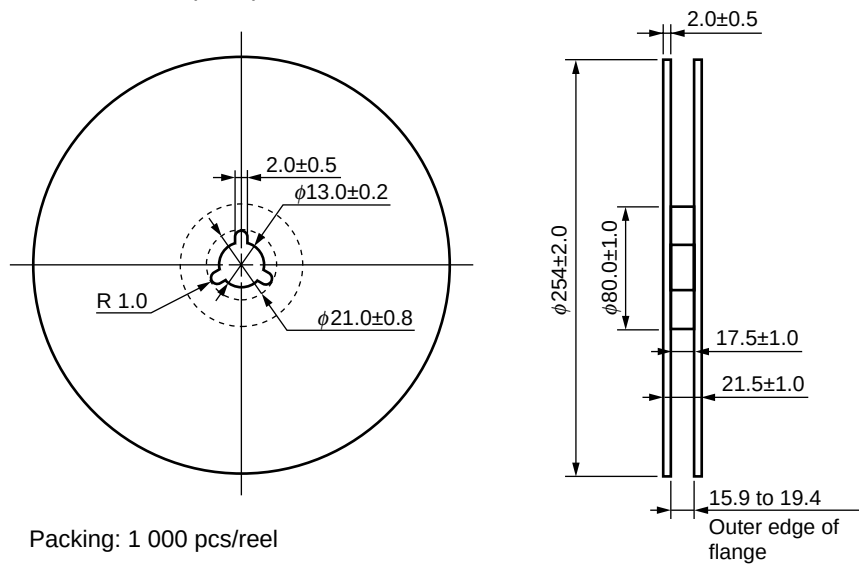
Tape Direction

PS2561AL-1-E3

PS2561AL-1-E4

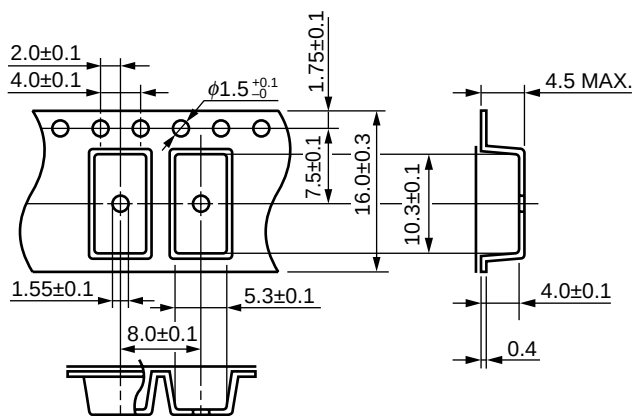


Outline and Dimensions (Reel)

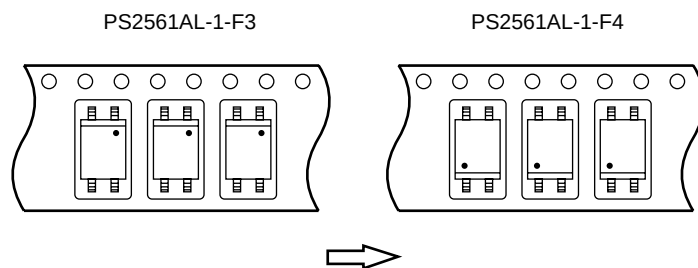


Packing: 1 000 pcs/reel

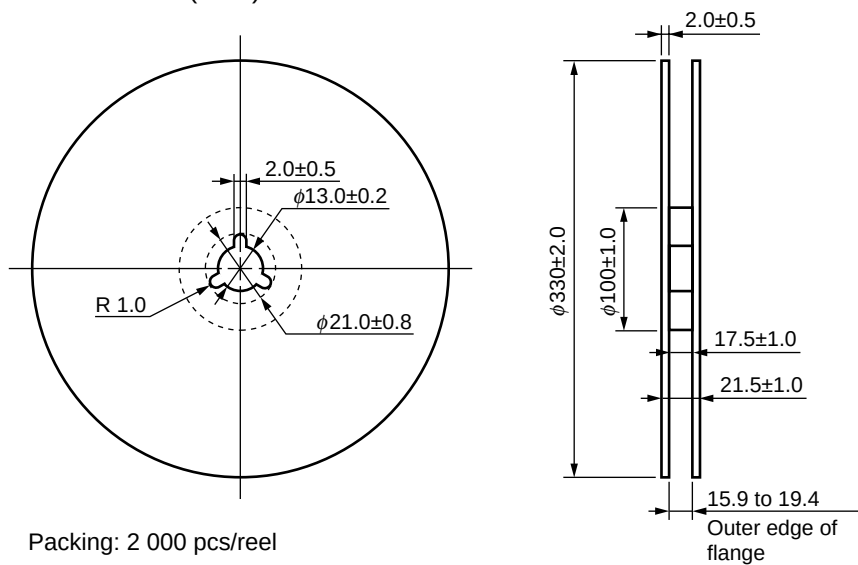
Outline and Dimensions (Tape)



Tape Direction

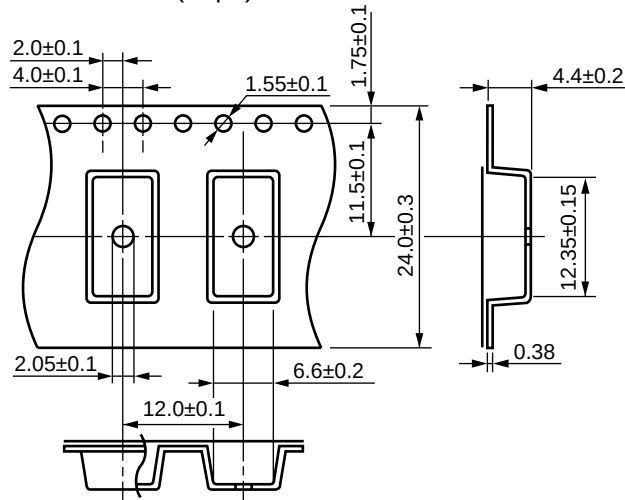


Outline and Dimensions (Reel)

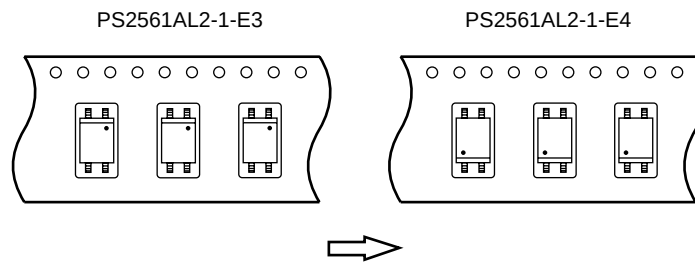


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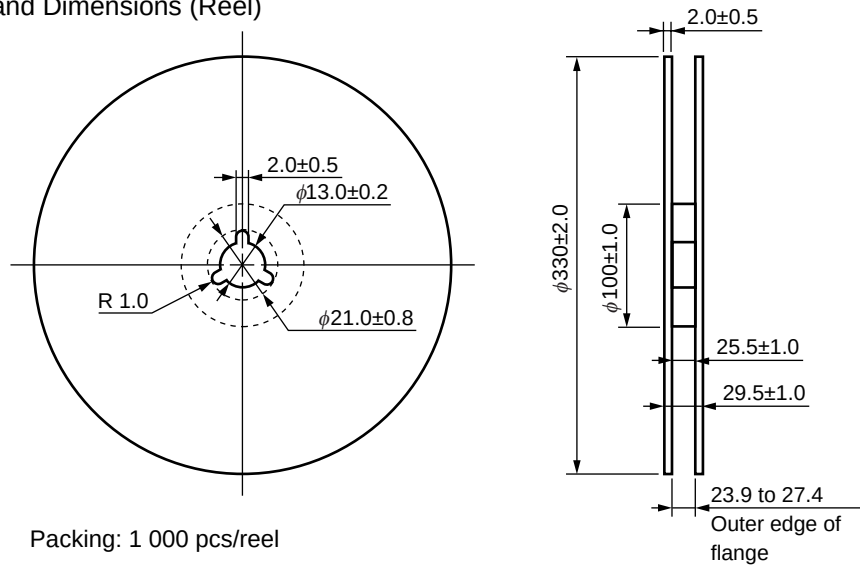
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



Packing: 1 000 pcs/reel

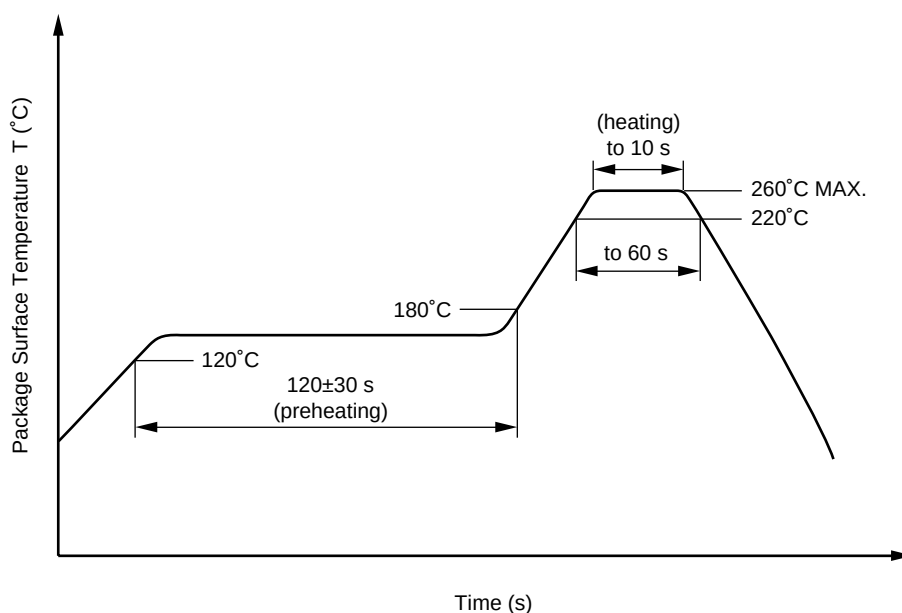
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220°C 60 seconds or less
- Time to preheat temperature from 120 to 180°C 120±30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260°C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

★ (3) Soldering by soldering iron

- Peak temperature (lead part temperature) 350°C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead.

(b) Please be sure that the temperature of the package would not be heated over 100°C.

(4) Cautions

- Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

★ **2. Cautions regarding noise**

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.

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M8E 00.4-0110

Caution	GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points. • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
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► For further information, please contact

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